

## 1.6mm Side Looking Phototransistor PT968-8C

### Features

- Fast response time
- High sensitivity
- Small junction capacitance
- Pb Free
- This product itself will remain within RoHS compliant version.

### Description

- PT968-8C is a phototransistor in miniature package which is molded in a water clear plastic with spherical top view lens. The device is spectrally matched to infrared emitting diode.

### Applications

- Optoelectronic switch
- VCR , Video Camera
- Floppy disk drive
- Infrared applied system

**Device Selection Guide**

Chip Materials	Lens Color
Silicon	Water clear

**Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Rating	Unit
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Collector-Voltage	$V_{ECO}$	5	V
Collector Current	$I_C$	20	mA
Operating Temperature	$T_{opr}$	-25~+85	°C
Storage Temperature	$T_{stg}$	-40~ +100	°C
Lead Soldering Temperature	$T_{sol}$	260	°C
Power Dissipation at (or below) 25°C Free Air Temperature	$P_c$	75	mW

**Notes:** \*1: Soldering time  $\leq$  5 seconds.

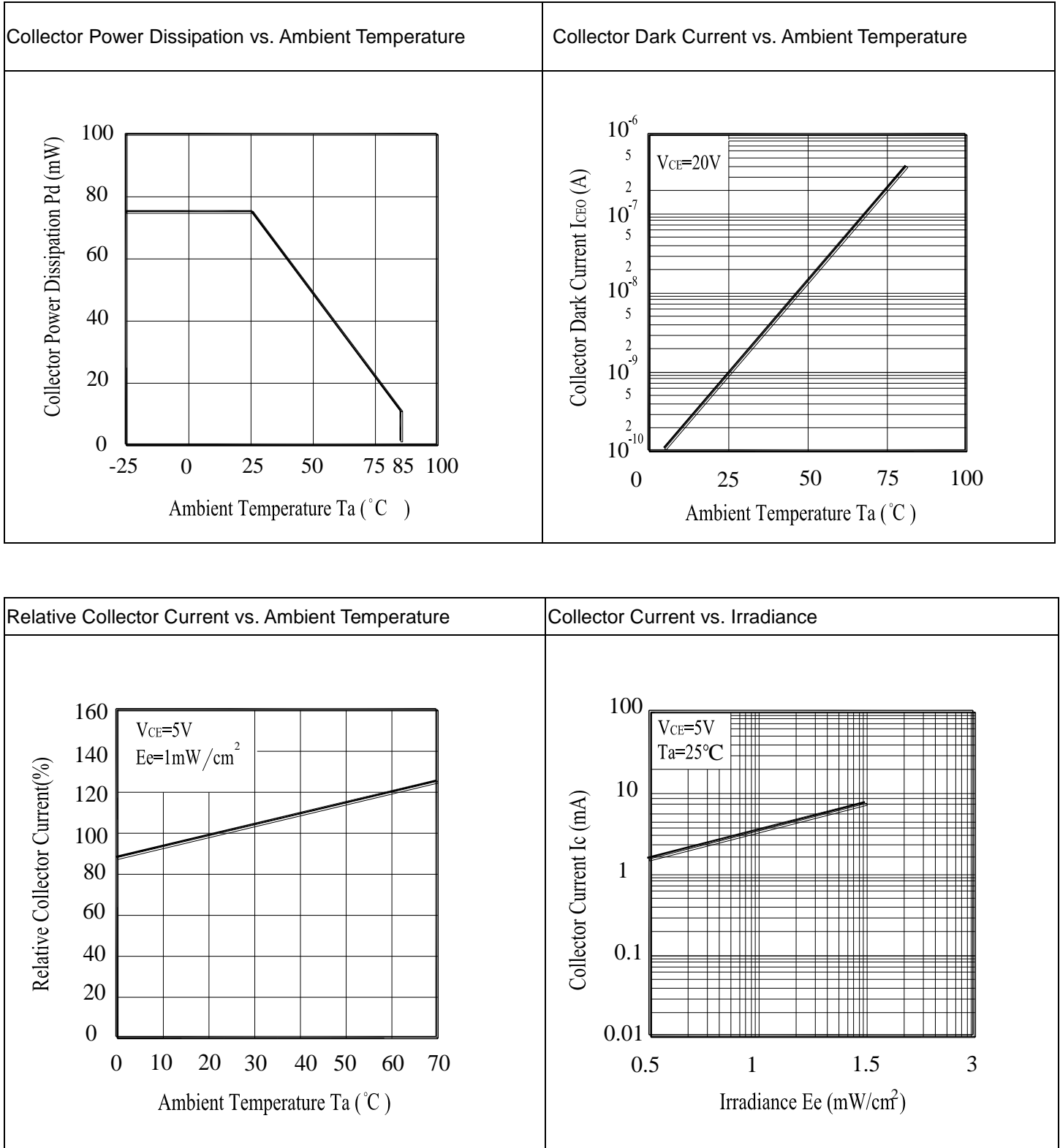
## Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Collector – Emitter Breakdown Voltage	$BV_{CEO}$	30	-----	-----	V	$I_C=100\mu A$ $E_e=0mW/cm^2$
Emitter-Collector Breakdown Voltage	$BV_{ECO}$	5	-----	-----	V	$I_E=100\mu A$ $E_e=0mW/cm^2$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	-----	-----	0.4	V	$I_C=2mA$ $E_e=1mW/cm^2$
Rise Time	$t_r$	-----	15	-----	$\mu S$	$V_{CE}=5V$ $I_C=1mA$ $RL=1000\Omega$
Fall Time	$t_f$	-----	15	-----		
Collector Dark Current	$I_{CEO}$	-----	-----	100	nA	$E_e=0mW/cm^2$ $V_{CE}=20V$
On State Collector Current	$I_{C(on)}$	1.59	-----	3.41	mA	$E_e=0.555mW/cm^2$ $V_{CE}=5V$
Rang Of Spectral Bandwidth	$\lambda_{0.5}$	400	-----	1100	nm	----
Wavelength of Peak Sensitivity	$\lambda_P$	-----	940	-----	nm	----
Half sensitivity angle	$2\theta_{1/2}$	-----	$\pm 11$	-----	Deg	----

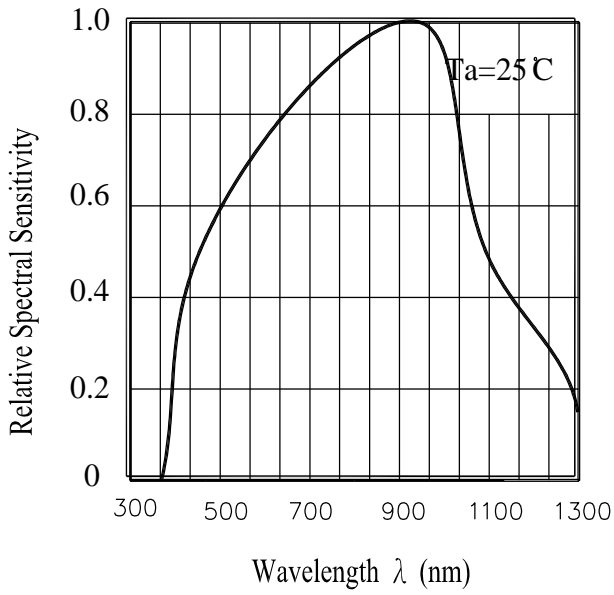
## Ranks

Parameter	Symbol	Min	Max	Unit	Test condition
6-2	IC (ON)	1.59	2.98	mA	VCE= 5 V E e = 0.555 mW/cm <sup>2</sup>
6-1		1.77	3.41		

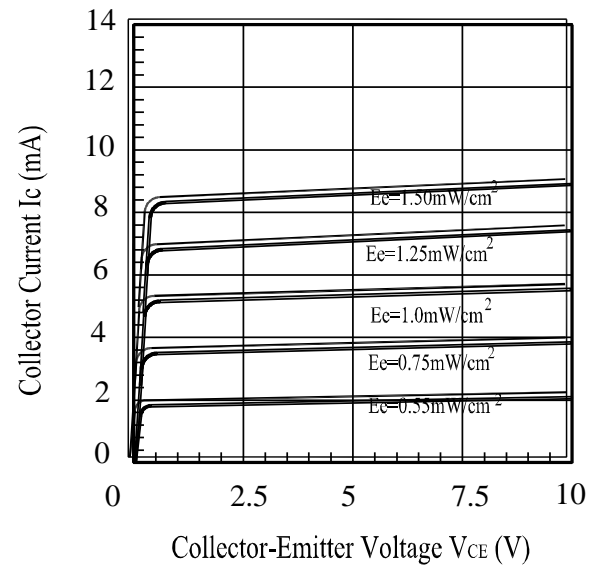
Typical Electro-Optical Characteristics Curves



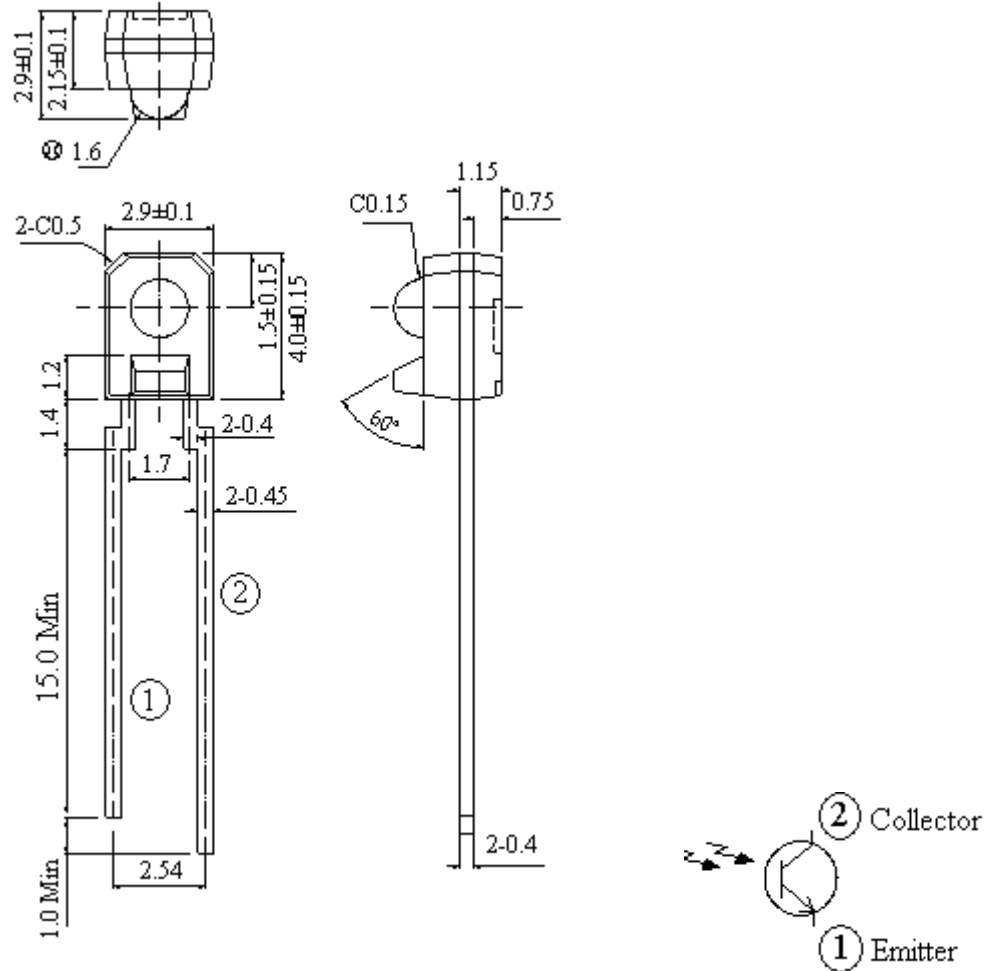
Spectral Sensitivity



Collector Current vs. Collector-Emitter Voltage



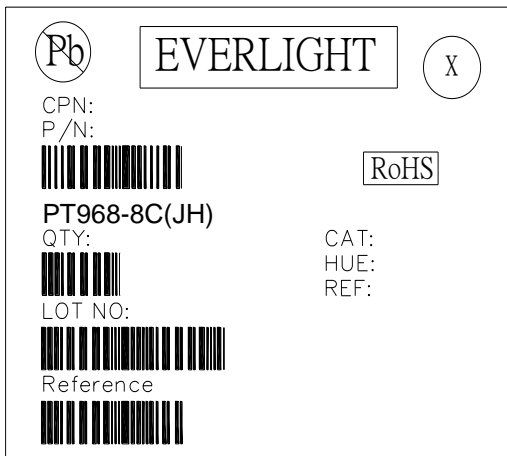
Package Dimension



Note: Tolerances unless dimensions  $\pm 0.25$ mm

**Packing Quantity Specification**

1. 1000PCS/1Bag,8Bags/1Box
2. 10Boxes/1Carton

**Label Explanation**

- CPN: Customer's Product Number
- P/N: Product Number
- QTY: Packing Quantity
- CAT: Luminous Intensity Rank
- HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- LOT No: Lot Number
- X: Month
- Reference: Identify Label Number

**Notes**

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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